UNISONIC TECHNOLOGIES CO., LTD

BCP68

NPN SILICON TRANSISTOR

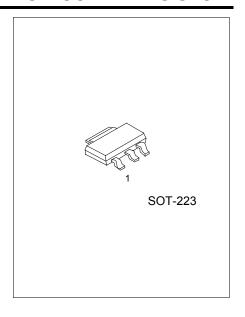
NPN MEDIUM POWER TRANSISTOR

FEATURES

- * High current (max. 1 A)
- * Low voltage (max. 20 V).
- * Complementary to UTC BCP69

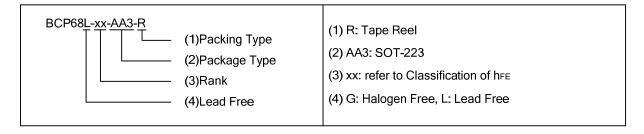
APPLICATIONS

* General purpose switching and amplification under high current conditions.



ORDERING INFORMATION

Ordering Number		Davis	Pin Assignment			Daaldaa	
Lead Free	Halogen Free	Package	1	2	3	Packing	
BCP68L-xx-AA3-R	BCP68G-xx-AA3-R	SOT-223	В	С	Е	Tape Reel	



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■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage (Ope	n Emitter)	V_{CBO}	32	V
Collector-Emitter Voltage (Open Base)		V_{CEO}	20	V
Emitter-Base Voltage (Open Collector)		V_{EBO}	5	V
Collector Current	DC	Ic	1	Α
	Peak	I _{CM}	2	Α
Peak Base Current		I _{BM}	200	mA
Total Power Dissipation (T _A ≤ 25°C)		P_D	1.35	W
Junction Temperature		TJ	150	$^{\circ}\!\mathbb{C}$
Operating Temperature		T _{OPR}	-45 ~ +150	$^{\circ}\!\mathbb{C}$
Storage Temperature		T _{STG}	-65 ~ +150	$^{\circ}\!\mathbb{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction To Ambient	θ_{JA}	91	°C/W

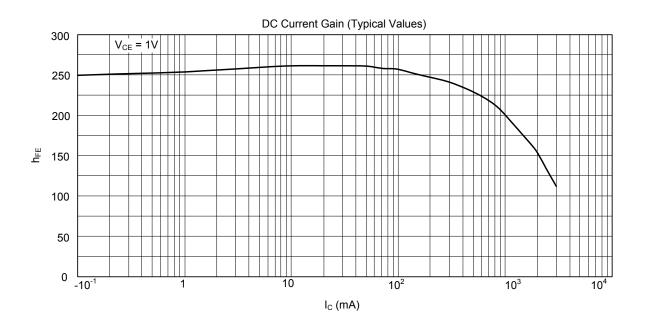
■ ELECTRICAL CHARACTERISTICS (T_J = 25°C, unless otherwise specified.)

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PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	I _C = 1A, I _B =100mA			500	mV
Dago Emitter Voltage	V_{BE}	$I_{\rm C}$ = 5mA, $V_{\rm CE}$ = 10V		620		mV
Base-Emitter Voltage		$I_C = 1A$, $V_{CE} = 1V$			1	V
O-11t	I _{CBO}	$I_E = 0, V_{CB} = 25V$			100	nA
Collector Cut-off Current		I _E = 0, V _{CB} = 25V, T _J = 150°C			10	μΑ
Emitter Cut-off Current	I _{EBO}	$I_{C} = 0, V_{EB} = 5V$			100	nA
		$I_{C} = 5mA, V_{CE} = 10V$	50			
DC Current Gain	h _{FE}	I _C = 500mA, V _{CE} = 1V	85		375	
		I _C = 1A, V _{CE} = 1V	60			
Collector Capacitance	Cc	$I_E = i_e = 0$, $V_{CB} = 5V$, $f = 1MHz$		48		pF
Transition Frequency	f_T	$I_C = -10$ mA, $V_{CE} = -5$ V, $f = 100$ MHz	40			MHz
DC Current Gain Ratio of the	h _{FE1}	U 1 - 0 5			1.6	
Complementary Pairs	h _{FE2}	I _C = 0.5A, V _{CE} = 1V			1.6	

■ CLASSIFICATION OF h_{FE}

RANK	16	25
RANGE	100~250	160~375

■ TYPICAL CHARACTERISTIC



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